Theory of Insulator M etal Transition and Colossal M agnetoresistance in Doped M anganites

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The persistent proxim ity of insulating and metallic phases, a puzzling characterestic of manganites, is argued to arise from the self-organization of the twofold degenerate \mathbf{e}_g orbitals of M n into localized Jahn-Teller(JT) polaronic levels and broad band states due to the large electron – JT phonon coupling present in them . We describe a new two band model with strong correlations and a dynamical mean-eld theory calculation of equilibrium and transport properties. These explain the insulator metal transition and colossal magnetoresistance quantitatively, as well as other consequences of two state coexistence.

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D oped perovskite m anganites R e $_{1\ x}$ A $_{x}$ M $\,$ nO $_{3}$, where Re and A are rare earth and alkaline earth ions, show a rich variety of electronic, magnetic and structural phenom ena and phases [1, 2]. Unusual e ects, such as insulator-metal (IM) transitions both as a function of x and oftem perature Tover awide region x 0.5, or even as a consequence of isotope substitution $(0^{18} ! 0^{16}) \beta$, colossal m agneto-resistance (CMR) near T_{IM} and 'm elting' of the charge/orbitally ordered insulator (x 2 0:5) into a metal in a relatively small(5-7 Tesla) magnetic eld all suggest that metallic and insulating phases are always very close in free energy. This is also re ected in the ubiquitous coexistence (static or dynamic) of two 'phases', one insulating with local lattice distortion and the other metallic without lattice distortion, with length scales varying from 10A to 10³A

These phenomena are due to the dynamics of the eq electrons of M n constrained by three strong on-site interactions, namely electron lattice or Jahn-Teller (JT) coupling which splits the twofold eq orbital degeneracy, ferrom agnetic e_g spin- t_{2g} spin exchange or H und's coupling $J_{\text{H}}\,$ and e_{q} electron repulsion U . The respective energies are $E_{\,\text{JT}}$ '0:5eV, J_{H} '2eV and U'5eV, compared to the eq electron intersite hopping t ' 02eV which sets the kinetic energy scale [4]. Understanding their observed consequences is one of the major challenges in the physics of strongly interacting electrons. Earlier theoretical attempts neglect one or more of these strong interactions and make further approximations; the predictions do not agree with many characteristics of manganites. For exam ple the ferrom agnetic Curie transition in a num ber of m anganites is from an insulator to a m etal, for 0.2° x $^{\circ}$ 0.5. However, a theory with just Hund's coupling, due to Furukawa [5], nds only a metallic phase, while Millis, Muller and Shraim an [6], who additionally include the electron-JT phonon coupling g but treat the JT distortions as static displacements, obtain a metalmetal transition crossing over to an insulator-insulator

transition as g increases.

We propose and implement here a new approach which incorporates the crucial elects of all the three interactions and is based on a new idea, namely that of coexisting JT polaronic and broad bandleg states, which we believe is the key to manganite physics. The idea and some of its consequences are described and calculations based on a new two band model are then outlined.

We rst discuss the e ect of large JT coupling g on the initially twofold degenerate e_g orbitals at each lattice site. There is one superposition (labelled ') which, when singly occupied, leads to a polaronic state with local octahedral symmetry breaking M n $\,$ 0 bond distortion and energy $\,$ $E_{\rm JT}$. Its intersite hopping is reduced (for (E $_{\rm JT}$ =h! $_0$) $\,$ 1 where ! $_0$ is the JT phonon mode frequency) by the exponential H uang-R hys [7] or phonon overlap factor ' exp ($E_{\rm JT}$ =2h! $_0$). Since ' exp(5) for LaM nO3, and being a local quantity

is not likely to change much on doping, the 'polaron bandwidth 2D $2zt ' k_B (125K)$ is small, and is neglected in much of this paper. At each site, there is necessarily another, orthogonal state (labelled b). Its energy is zero on the fraction x of sites where the 'electrons are not present (hole-sites), and is $U = (U + 2E_{JT})$ on the 'electron sites. The b electron hops adiabatically $\binom{1}{0}$, in an annealed random medium of repulsive 'sites and (for a hom ogeneous orbital liquid) form sa band whose re-normalized bandwidth 2D increases with ${\tt x}$ as well as with T 1 and H . For, the inhibition of b hopping due to large U is reduced when there are more hole-sites, and that due to large J_H is reduced when the t_{2q} spin order is enhanced W e show in this paper that the sim ultaneous presence of 'polaron states and the bband, the change in the e ective band width of the latter with x;T;H etc. and the consequent change in their relative occupation (leading to an insulator eg for $E_{\rm JT}$ > D and m etal for $E_{\rm JT}$ < D) are the basis of m any phenom ena seen in manganites. Our picture requires the persistence of local JT distortions well into the metallic regime, as indeed seen by direct probes of instantaneous M n 0 bond length [8]. The 'polaron motion is anti-adiabatic (2D h!₀) while the belectron motion is adiabatic (2D h!₀); the respective bandwidths are exponentially small and of order the bare value. By contrast, in earlier theoretical work [6, 9] where the JT distortion is treated as static, both 'and belectron dynamics become adiabatic so that the bands are of comparable width, leading to consequences which disagree with experiment.

The system of correlated 'and b states described above can be modelled by the Hamiltonian

In Eq.(1), the 'polaron has energy ($E_{\rm JT}$), the b electrons hop between nearest neighbour sites with an e ective amplitude t, and U is the electron equilibrium between 'polarons and belectrons of the same spin at a particular site [10]. The common chemical potential is . H $_{\rm m}$ is the magnetic part involving the $e_{\rm g}$ spins $s_{\rm i}$ and $t_{\rm 2g}$ core spins $S_{\rm i}$, namely

$$H_{m} = J_{H} S_{i} S_{i} J_{F} S_{i} S_{j} S_{j} S_{i} H (2)$$

In addition to the fam iliar H und's coupling J_H and Zeem an coupling to an external eld H̃ (neglecting the relatively smaller term $_B$ \mathbf{s}_1 H̃) we have included in H $_m$ a new ferrom agnetic nearest neighbour exchange J_F between the t_{2g} core spins.

The new term arises from a virtual double-exchange process in which an 'electron at a site i hops quickly (adiabatically) to a nearest neighbour site j and back. In the limit of large U and J_H , and approximating the t_{2g} spins as classical, i.e., $S_i = S \ ^i_i$ where i_i are unit vectors, the energy shift to second order in t is $t^2 = 2E_{JT} \ \frac{1}{2} \ (^i_i \ ^j + 1) \ (n_{\dot{i}} \ (1 \ n_j) + n_{\dot{j}} \ (1 \ n_i)).$ The energy denominator $2E_{JT}$ arises from the unrelaxed JT distorted intermediate state, the $\frac{1}{2} \ (^i_i \ ^j + 1)$ factor from large J_H , and the occupancy dependent terms from large U. We have further approximated this by the simple exchange term in Eq.(2), whence J_F ' $t^2 = (2E_{JT} \ S^2) \ x \ (1 \ x)$.

The model Ham iltonian H $_{^{1}\!D}$ (Eq.(1)) can be motivated starting from a lattice model with two e_g orbitals per site[1, 2]. Let a_i^y create an electron in orbital at site i, (with $j=1>jx^2$ $y^2>$ and $j=2>jBz^2$ $f^2>$ say), locally coupled to JT lattice modes $(Q_{xi};Q_{zi})$ $(Q_{i};_i)$ by the term H $_{\rm JT}^i=ga_i^y\sim a_i$ Q_i where \sim are the Paulim atrices. The eigenvalues of H $_{\rm JT}^i$ are gQ_i , the corresponding electron creation operators being labelled by and $^{^{\rm ty}}$. The electron of these states are

 $(K = 2)Q_{i}^{2}$ gQi where K is the phonon force constant. The lower (') branch has a minimum at a static lattice distortion $Q_0 = g=K$ and energy $E_{JT} =$ $(g^2=2K)$. $\stackrel{\mathbf{V}}{:}$ in Eq.(1) are polaron creation operators given by $\stackrel{\wedge}{:}$ where ^; ($\exp(iQ_0P_i=h)$ where P_i is the radial momentum conjugate to Q_i) are unitary Lang-Firsov [11] like displacem ent transform ations. The exponential rein the hopping am plitude of 'arises essentially from their ground state average. (We neglect the small uctuations with respect to this average). No lattice distortion or reduction in hopping is associated with the higher (b) branch. The small leading intersite term $t = hiji = hiji = hiji + b_i^y + hc$ describing 'b hybridization is not included in Eq.(1); som e consequences are discussed later. Thus for $(E_{JT} = h!_0)$ 1, and neglecting H $_{1b}^{0}$, we are led to Eq (1). We have made further approximations which are realistic for a homogenous orbital liquid, by statistically averaging quantities which depend on the orbital admixture angle fig, eg the intersite hopping and the nearest neighbour M n 0 bond correlations (short-long), so that t and by are to be regarded as averaged over f $_{ig}$. This is reasonable for 0.2×0.5 in most manganites, but poor for those other values of x for which one has strong orbital correlations or long range orbital order. Finally, in this regime, the chemical potential is chosen such that

$$h_{i}i + h_{b}i = n + n_{b} = (1 x)$$
 (3)

We have calculated the equilibrium and transport properties of H b (Eq.(1)) using the dynamical mean eld theory (DMFT) [12] which is exact in d = 1, and is accurate in three dim ensions if spatial correlations are not crucial. H b, being a generalized form of the Falicov-K im ball m odel[13] with additional spin interactions H $_{\rm m}$ (Eq.(2)) and constraint Eq.(3), is exactly soluble in this $\lim it$ [12]. We treat the t_{2g} core spins as classical as stated earlier, and their interaction in the Curie-Weiss m ean eld approximation, and work in the large J_H lim it (i.e. $SJ_H = t$ 1). The local self energy $_{ii}(!^+)$ of the b electrons and the mean magnetization $m = h_i^i$ are determ ined self-consistently. From these we calculate the spectral density or density of states (DOS) b(!) of the b electrons which determ ines their occupation relative to that of the 'state, the current-current correlation function relevant for the K ubo form ula for the electrical conductivity, etc[14]. Most of our calculations use a sem icircular bare DOS with a bare bandwidth 2D $_{\rm o}$ [15].

Our results for $_{\rm b}$ (!) for di erent values of x and T are shown in Fig.1. Since the elective bandwidth 2D of the belectrons decreases signicantly as x decreases (for any sizeable U), the b band bottom is above the 'level for small x e.g x = 0:1 (Fig.1a), and the low temperature state is an insulator, ferrom agnetic because of $J_{\rm F}$. (We ignore the anti-ferrom agnetic super-exchange as it is dominated by the much larger $J_{\rm F}$ for x $^{>}$:1). On

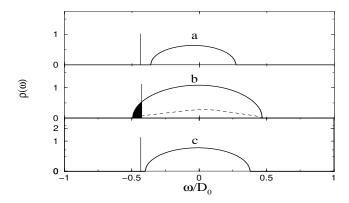


FIG. 1: Spectral density or b-D O S $_{\rm b}$ (!) for various values of doping x and tem perature T . The e ective 'polaron level is marked as a vertical line. Param eters chosen are E $_{\rm JT}$ = 0.5 eV , D $_{\rm o}$ = 1.2 eV , U = 5.0 eV J $_{\rm F}$ = 2.23 m eV . (a) x = 0.1, T = 0, = E $_{\rm JT}$; ferrom agnetic insulator. (b) x = 0.3, T = 180K (< T $_{\rm c}$ = 240K); ferrom agnetic m etal. (c) x = 0.3, T = 350K; param agnetic insulator. Full(dotted) lines correspond to up (down) spin D O S . O ccupied band states are shown shaded.

increasing x, D increases as well, and beyond a critical x_c for which D = E_{JT} , the low temperature state is a ferrom agnetic m etal, as in Fig.1b. W e note that while both b and 'states are occupied in the metal, most electrons are in the latter, polaronic state since $n_1 = 0.66$ and $n_b = 0.04$. T_c is largely due to J_F ; for, n_b being very small, so is the belectron contribution to Tc via conventional double exchange. On increasing T at this x, the t2g spins disorder, reducing the e ective b electron hopping or D . Fig.1c shows the DOS at T = 350K (> T_c). It is that of a small gap sem iconductor. The metal insulator transition occurs very near T_c because of the strong feedback between D and the magnetization m. The carriers in the paramagnetic state are belectrons excited across the relatively smalle ective band gap, not thermally unbound small polarons. The mobile carrier fraction n_b is very small in the metallic phase $(n_b ' 0.06)$ for parameters corresponding to La_{0:7}Sr_{0:3}M nO₃) and decreases rapidly [14] to a minimum at Tc, whereas the electron density is 0.7 per site. This is exactly the hitherto unexplained inference for neff from the observed D rude weight in this compound [16].

Our theory also describes transport properties fairly well. Fig.2 shows the electrical resistivity (T) versus T for model param eters chosen to t $T_{\rm c}$ and ($T_{\rm c}$) for La_{0:67}Ca_{0:33}M nO₃ [17]. The results for semicircular DOS and tight binding DOS are nearly the same. We see clearly the sharp param agnetic insulator to ferrom agnetic metal transition, the former having a calculated electrical gap eff of 34 meV while the experimental value is 48 meV [18]. The resistivity falls dram atically to about 2 m cm just below T c and does not decrease much further thereafter, in contrast to the observed residual re-

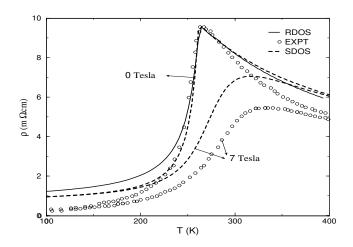


FIG. 2: The resistivity (T) of La_{1 x}Ca_xM nO₃ (x = 0.33) as a function of temperature T. Calculated (full lines for realistic anisotropic hopping, dotted lines for a semicircular DOS) and experimental (circles, from ref.[17]) results for H = 0 and 7Tesla are shown. Parameters, chosen to t T_c and (T_c), are E_{JT} = 0.5 eV (SDOS), 0.6 eV (RDOS), 2D_o = 2.4 eV (SDOS), 2.44 eV (RDOS), U = 5 eV, and J_F = 2.37 m eV.

sistivity values which can be as small as 50 cm. This is a consequence of our neglect of inter-site 'coherence and is discussed later. The resistivity in a eld of 7 Tesla is also shown in Fig 2. The colossal decrease (CMR) is apparent [18].

The properties of manganites vary strongly and characteristically with the ionic species Re and A. This is natural in our model, since the relative balance between metal and insulator is strongly a ected by small changes in E $_{\mbox{\scriptsize JT}}\,$ and D $_{\mbox{\scriptsize o}}$ and the carrier density depends exponentially on (D E_{JT}). For example, keeping E_{JT} xed (for a given x = 0.3 say), and $varying 2D_0$, we nd the variations in physical properties shown in Fig 3. T_c , being proportional to J_F , increases roughly as D_0^2 . The Curie transition changes from insulator-insulator to insulator-m etalto m etal-m etal, as is seen experim entally in the sequence P r_{0:7}C a_{0:3}M nO₃; La_{0:7}C a_{0:3}M nO₃ and $\text{La}_{0:7}\text{Sr}_{0:3}\text{M}~\text{nO}_3$. D $_{\text{o}}$ is believed [19] to increase in this order. We also exhibit the enormous variation in the calculated fractional magneto-resistance f R (H)=R (H)g $_{T=T_{c}}$ for H = 7 T esla as a function of T_c ; the agreem ent with experim ent [20] is very good.

Thus, in the regime 0.2 < x < 0.4, a wide range of physical properties for a num ber of doped m anganites can be understood physically and described quantitatively by our theory [14]. The ratio (E $_{\rm JT}$ =D $_{\rm o}$) broadly determ ines the system atics and D $_{\rm o}$ the basic energy scale (J $_{\rm H}$ and U being close to 1 for our purposes).

The intersite hopping of the 'polarons arising from term H $_{1D}^{0}$, with a characteristic temperature scale of T (z t=k_B) ' 125K , has many important consequences. Below T the 'states can form a coherent band

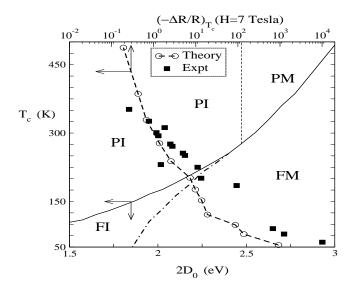


FIG. 3: Physical properties as a function of the d electron bandwidth 2D $_{\text{O}}$, for xed E $_{\text{JT}}=0.5\,\text{eV}$. Full line: ferrom agnetic T $_{\text{C}}$ vs D $_{\text{O}}$. The resistive transition is from an insulator to an insulator (P I+F I) for small D $_{\text{O}}$, from an insulator to a metal(P I+F M) for intermediate D $_{\text{O}}$, and from a metal to a metal(P M-F M) for large D $_{\text{O}}$, as indicated . Broken line: calculated fractionalm agnetoresistance (R (H)=R (H)) $_{\text{T}_{\text{C}}}$ vs T $_{\text{C}}$ for H = 7 T esla . Experimental points are from [20].

due to hybridization with b states, whence the JT distortion can become dynamic (time scale $h=k_{\rm B}\,T$), and also smaller self-consistently. The b electron scattering and the consequent resistivity then vanish at T = 0, and are nonzero only if static disorder is present. This can lead to a metallic state with a small residual resistivity or to an Anderson localized insulating state depending on the amount of disorder. The strong dependence of T_c on isotope mass M $_0$ is also a consequence of 'polaron hopping, since its direct double exchange contribution to T_c will be proportional to t(1 $\,$ x)exp($\,E_{\rm JT}=2h\,!_{\,0})$ and $!_{\,0}=\,^{1}$ K =M $_{\,0}$. The isotope e ect thus estimated is of the right size [21].

Spatial correlations and inhom ogeneities can be investigated in an extended version of the model in Eq.(1) by including the orbital angles $\,_{\mathrm{i}}$ as additional degrees of freedom. The intersite hopping t_{ij} now depends on iand i. There are a number of anham onic, steric, elastic term s, eq., nearest neighbour long-short M n correlations, coupling between JT modes and strain, etc., which depend on these angles as well. These, and other factors such as the variation of E_{JT} with local ion size, can be included in Eq.(1), and questions such as short range correlation, orbital order, long range order in n_{bi}) (total charge/relative charge order), disorder induced 'phase' separation, explored by going beyond the self-consistent single site DMFT used here. It would also be interesting to explore the idea of exponentially separated time scales and adiabatic - nonadiabatic crossover

in other oxides and organic m olecules w ith orbital degeneracy and strong local sym m etry breaking Jahn Teller coupling.

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